SLLS847D - JULY 2007 - REVISED NOVEMBER 2012

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5-V DUAL RS-232 LINE DRIVER/RECEIVER WITH ±15-kV ESD PROTECTION

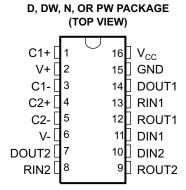
Check for Samples: TRS202E

FEATURES

- IEC61000-4-2 (Level 4) ESD Protection for RS-232 Bus Pins
 - ±8-kV Contact Discharge
 - ±15-k-V Air-Gap Discharge
 - ±15-kV Human-Body Model
- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- Operates at 5-V V_{CC} Supply
- · Operates Up To 120 kbit/s
- External Capacitors . . . 4 × 0.1 μF or 4 × 1 μF
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

APPLICATIONS

- Battery-Powered Systems
- PDAs
- Notebooks
- Laptops
- Palmtop PCs
- Hand-Held Equipment



DESCRIPTION/ORDERING INFORMATION

The TRS202E device consists of two line drivers, two line receivers, and a dual charge-pump circuit. TRS202E has IEC61000-4-2 (Level 4) ESD protection pin-to-pin (serial-port connection pins, including GND). The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 5-V supply. The device operates at data signaling rates up to 120 kbit/s and a maximum of 30-V/µs driver output slew rate.

The TRS202E can work with both 0.1-µF or 1-µF external capacitors.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



ORDERING INFORMATION

T _A	PA	CKAGE ⁽¹⁾ (2)	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	PDIP – N	Tube of 25	TRS202ECN	TRS202ECN
	SOIC – D	Tube of 40	TRS202ECD	TRECORDE
	201C - D	Reel of 2500	TRS202ECDR	TRS202EC
0°C to 70°C	SOIC - DW	Tube of 40	TRS202ECDW	TRESOSEC
	30IC - DW	Reel of 2000	TRS202ECDWR	TRS202EC
	TSSOP – PW	Tube of 90	TRS202EPW	DUIGOEC
		Reel of 2000	TRS202EPWR	RU02EC
	PDIP – N	Tube of 25	TRS202EIN	TRS202EIN
	SOIC - D	Tube of 40	TRS202EID	TRS202EI
	201C – D	Reel of 2500	TRS202EIDR	TR3202EI
-40°C to 85°C	SOIC - DW	Tube of 40	TRS202EIDW	TDC202FI
	30IC - DW	Reel of 2000	TRS202EIDWR	TRS202EI
	TSSOP – PW	Tube of 90	TRS202EIPW	PLIOSEI
	1330F - PW	Reel of 2000	TRS202EIPWR	RU02EI

- (1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.
- (2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

FUNCTION TABLES

Each Driver⁽¹⁾

INPUT D _{IN}	OUTPUT D _{OUT}
L	Н
Н	L

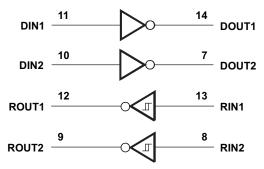
(1) H = high level, L = low level

Each Receiver(1)

INPUT R _{IN}	OUTPUT R _{OUT}
L	Н
Н	L
Open	Н

(1) H = high level, L = low level, Open = input disconnected or connected driver off

Figure 1. LOGIC DIAGRAM (POSITIVE LOGIC)



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Absolute Maximum Ratings (1) (2)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range (2)		-0.3	6	V
V+	Positive charge pump voltage range (2)		V _{CC} - 0.3	14	V
V-	Negative charge pump voltage range	Negative charge pump voltage range		0.3	V
	Input voltage range	Drivers	-0.3	V+ + 0.3	V
VI		Receivers		±30	V
.,	Output valle as yours	Drivers	V0.3	V+ + 0.3	1/
Vo	Output voltage range	Receivers	-0.3	V _{CC} + 0.3	V
D _{OUT}	Short-circuit duration			Continuous	
T_{J}	Operating virtual junction temperature			150	°C
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Package Thermal Impedance

over operating free-air temperature range (unless otherwise noted)

				UNIT
		D package	73	
	Package thermal impedance (1) (2)	DW package	57	°C/W
θ_{JA}		N package	67	C/VV
		PW package	108	

 ⁽¹⁾ Maximum power dissipation is a function of T_{J(max)}, θ_{JA}, and T_A. The maximum allowable power dissipation at any allowable ambient temperature is PD = (T_{J(max)} - T_A)/θ_{JA}. Operating at the absolute maximum T_J of 150°C can affect reliability.
 (2) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions⁽¹⁾

(see Figure 5)

(19410 0)		MIN	NOM	MAX	UNIT
	Supply voltage		4.5	5	5.5	V
V _{IH}	Driver high-level input voltage	D _{IN}	2			V
V_{IL}	Driver low-level input voltage	D _{IN}			0.8	V
.,	Driver input voltage	D _{IN}	0		5.5	V
VI	Receiver input voltage		-30	5.5	V	
_	Operating free-air temperature	TRS202EC	0		70	00
IA		TRS202EI	-40		85	°C

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 5 V ±0.5 V.

Electrical Characteristics(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

F	ARAMETER	TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
I _{CC} Suppy co	rrent	No load, V _{CC} = 5 V		8	15	mA

Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 5 V + 0.5 V. All typical values are at V_{CC} = 5 V, and T_A = 25°C.

All voltages are with respect to network GND.



DRIVER SECTION

Electrical Characteristics(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TEST CON	DITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
V_{OH}	High-level output voltage	D_{OUT} at $R_L = 3 k\Omega$ to GND	, D _{IN} = GND	5	9		V
V_{OL}	Low-level output voltage	D_{OUT} at $R_L = 3 k\Omega$ to GND	, $D_{IN} = V_{CC}$	-5	-9		V
I _{IH}	High-level input current	$V_I = V_{CC}$			15	200	μA
I_{IL}	Low-level input current	V _I at 0 V			-15	-200	μΑ
I _{OS} (3)	Short-circuit output current	V _{CC} = 5.5 V	V _O = 0 V		±10	±60	mA
r _o	Output resistance	V _{CC} , V+, and V- = 0 V	V _O = ±2 V	300			Ω

Switching Characteristics⁽¹⁾

over recommended ranges of suply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

PARAMETER		TEST CO	TEST CONDITIONS		TYP ⁽²⁾	MAX	UNIT
	Maximum data rate	C _L = 50 to 1000 pF, One D _{OUT} switching,	$R_L = 3 \text{ k}\Omega \text{ to 7 k}\Omega,$ See Figure 2	120			kbit/s
t _{PLH(D)}	Propagation delay time, low- to high-level output	C _L = 2500 pF, All drivers loaded,	$R_L = 3 \text{ k}\Omega$, See Figure 2		2		μs
t _{PHL(D)}	Propagation delay time, high- to low-level output	C _L = 2500 pF, All drivers loaded,	$R_L = 3 \text{ k}\Omega$, See Figure 2		2		μs
t _{sk(p)}	Pulse skew ⁽³⁾	C _L = 150 to 2500 pF,	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega,$ See Figure 3		300		ns
SR(tr)	Slew rate, transition region (see Figure 2)	C _L = 50 to 1000 pF, V _{CC} = 5 V	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega,$	3	6	30	V/µs

ESD Protection

PIN	TEST CONDITIONS	TYP	UNIT
	Human-Body Model	±15	
D _{OUT} , R _{IN}	Contact Discharge	±8	kV
	Air-gap Discharge	±15	

 ⁽¹⁾ Test conditions are C1–C4 = 0.1 μF at V_{CC} = 5 V + 0.5 V.
 (2) All typical values are at V_{CC} = 5 V, and T_A = 25°C.
 (3) Short-circuit durations should be controlled to prevent exceeding the device absolute power-dissipation ratings, and not more than one output should be shorted at a time.

Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 5 V + 0.5 V. All typical values are at V_{CC} = 5 V, and T_A = 25°C. Pulse skew is defined as |t_{PLH} - t_{PHL}| of each channel of the same device.

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RECEIVER SECTION

Electrical Characteristics(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TEST	CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
V _{OH}	High-level output voltage	$I_{OH} = -1 \text{ mA}$		3.5	V _{CC} - 0.4		V
V _{OL}	Low-level output voltage	I _{OL} = 1.6 mA				0.4	V
V _{IT+}	Positive-going input threshold voltage	V _{CC} = 5 V,	T _A = 25°C		1.7	2.4	V
V_{IT-}	Negative-going input threshold voltage	$V_{CC} = 5 V$,	$T_A = 25^{\circ}C$	0.8	1.2		V
V _{hys}	Input hysteresis (V _{IT+} – V _{IT-})			0.2	0.5	1	V
rį	Input resistance	V _I = ±3 V to ±25 \	/	3	5	7	kΩ

Test conditions are C1–C4 = 0.1 μF at V_{CC} = 5 V + 0.5 V. All typical values are at V_{CC} = 5 V, and T_A = 25°C.

Switching Characteristics⁽¹⁾

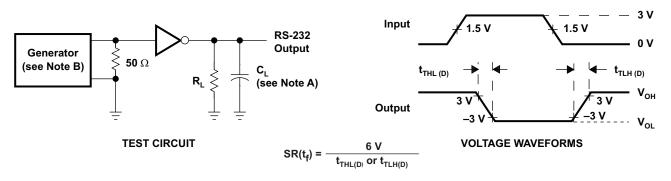
over recommended ranges of suply voltage and operating free-air temperature (unless otherwise noted) (see Figure 4)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
t _{PLH(R)}	Propagation delay time, low- to high-level output	$C_{L} = 150 \text{ pF}$		0.5	10	μs
t _{PHL(R)}	Propagation delay time, high- to low-level output	C _L = 150 pF		0.5	10	μs
t _{sk(p)}	Pulse skew ⁽³⁾			300		ns

Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 5 V + 0.5 V. All typical values are at V_{CC} = 5 V, and T_A = 25°C. Pulse skew is defined as $|t_{PLH}-t_{PHL}|$ of each channel of the same device.



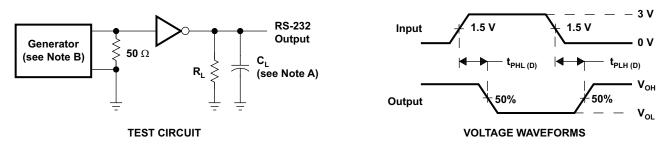
PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 120 kbit/s, $Z_O = 50 \Omega$, 50% duty cycle, $t_f \le 10$ ns.

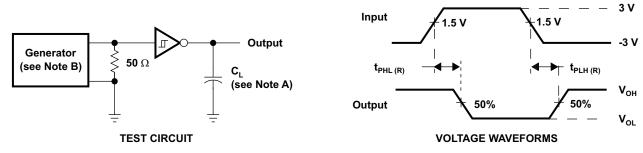
Figure 2. Driver Slew Rate



NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 120 kbit/s, $Z_O = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns. $t_f \le 10$ ns.

Figure 3. Driver Pulse Skew



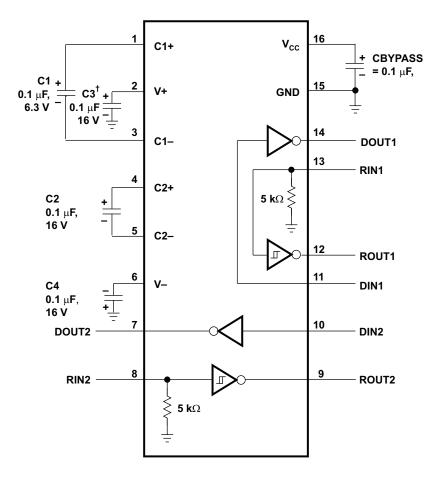
NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns. $t_f \le 10$ ns.

Figure 4. Receiver Propagation Delay Times



APPLICATION INFORMATION



C3 can be connected to V_{CC} or GND.

NOTES: A. Resistor values shown are nominal.

B. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.

Figure 5. Typical Operating Circuit and Capacitor Values

Capacitor Selection

The capacitor type used for C1-C4 is not critical for proper operation. The TRS202E requires $0.1-\mu F$ capacitors, although capacitors up to 10 μF can be used without harm. Ceramic dielectrics are suggested for the $0.1-\mu F$ capacitors. When using the minimum recommended capacitor values, make sure the capacitance value does not degrade excessively as the operating temperature varies. If in doubt, use capacitors with a larger (e.g., $2\times$) nominal value. The capacitors' effective series resistance (ESR), which usually rises at low temperatures, influences the amount of ripple on V+ and V-.

Use larger capacitors (up to 10 µF) to reduce the output impedance at V+ and V-.

Bypass V_{CC} to ground with at least 0.1 μ F. In applications sensitive to power-supply noise generated by the charge pumps, decouple V_{CC} to ground with a capacitor the same size as (or larger than) the charge-pump capacitors (C1–C4).

ESD Protection

TI TRS202E devices have standard ESD protection structures incorporated on the pins to protect against electrostatic discharges encountered during assembly and handling. In addition, the RS232 bus pins (driver outputs and receiver inputs) of these devices have an extra level of ESD protection. Advanced ESD structures were designed to successfully protect these bus pins against ESD discharge of ±15-kV when powered down.



ESD Test Conditions

Stringent ESD testing is performed by TI, based on various conditions and procedures. Please contact TI for a reliability report that documents test setup, methodology, and results.

Human-Body Model (HBM)

The HBM of ESD testing is shown in Figure 6. Figure 7 shows the current waveform that is generated during a discharge into a low impedance. The model consists of a 100-pF capacitor, charged to the ESD voltage of concern, and subsequently discharged into the device under test (DUT) through a $1.5-k\Omega$ resistor.

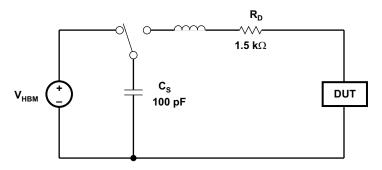


Figure 6. HBM ESD Test Circuit

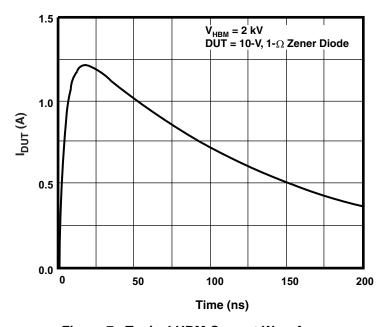


Figure 7. Typical HBM Current Waveform

Machine Model (MM)

The MM ESD test applies to all pins using a 200-pF capacitor with no discharge resistance. The purpose of the MM test is to simulate possible ESD conditions that can occur during the handling and assembly processes of manufacturing. In this case, ESD protection is required for all pins, not just RS-232 pins. However, after PC board assembly, the MM test no longer is as pertinent to the RS-232 pins.

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REVISION HISTORY

CI	hanges from Revision C (May 2010) to Revision D	Page
•	Fixed I _{OS} values typo in Electrical Characteristics table, changed – to ±.	4





10-Jun-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Sample
TRS202ECD	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TRS202EC	Sample
TRS202ECDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TRS202EC	Sample
TRS202ECDRG4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TRS202EC	Sample
TRS202ECDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TRS202EC	Sample
TRS202ECDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	TRS202EC	Sample
TRS202ECN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TRS202ECN	Sample
TRS202ECNE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	TRS202ECN	Sample
TRS202ECPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	RU02EC	Sample
TRS202ECPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	RU02EC	Sample
TRS202ECPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	RU02EC	Sample
TRS202EID	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TRS202EI	Sample
TRS202EIDR	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TRS202EI	Sample
TRS202EIDW	ACTIVE	SOIC	DW	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TRS202EI	Sample
TRS202EIDWR	ACTIVE	SOIC	DW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TRS202EI	Sample
TRS202EIN	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	TRS202EIN	Sample
TRS202EINE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	TRS202EIN	Sample
TRS202EIPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	RU02EI	Sample



PACKAGE OPTION ADDENDUM

10-Jun-2014

Orderable Device	Status	Package Type	_	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
TRS202EIPWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	RU02EI	Samples
TRS202EIPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	RU02EI	Samples
TRS202EIPWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	RU02EI	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.



PACKAGE OPTION ADDENDUM

10-Jun-2014

In no event shall TI's liabilit	v arising out of such information	exceed the total purchase price	ce of the TI part(s) at issue in th	is document sold by TI to Cu	stomer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com 2-Nov-2012

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TRS202ECDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TRS202ECDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
TRS202ECPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TRS202EIDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
TRS202EIDWR	SOIC	DW	16	2000	330.0	16.4	10.75	10.7	2.7	12.0	16.0	Q1
TRS202EIPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

www.ti.com 2-Nov-2012



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TRS202ECDR	SOIC	D	16	2500	367.0	367.0	38.0
TRS202ECDWR	SOIC	DW	16	2000	367.0	367.0	38.0
TRS202ECPWR	TSSOP	PW	16	2000	367.0	367.0	35.0
TRS202EIDR	SOIC	D	16	2500	367.0	367.0	38.0
TRS202EIDWR	SOIC	DW	16	2000	367.0	367.0	38.0
TRS202EIPWR	TSSOP	PW	16	2000	367.0	367.0	35.0

D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AA.



DW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC—7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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